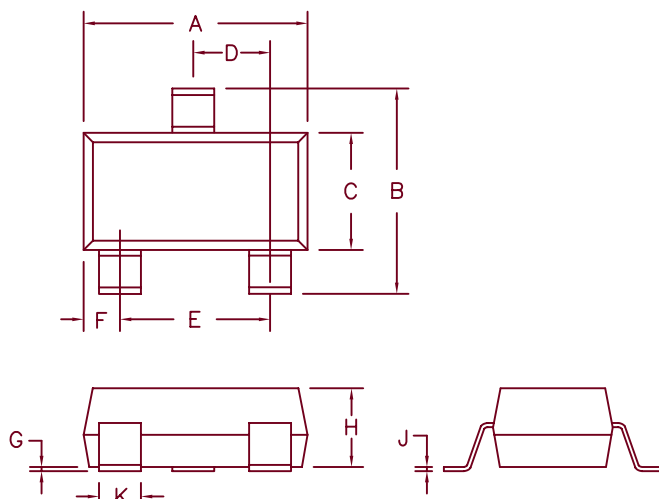


200 mW Schottky Diode

BAT54, BAT54A, BAT54C, BAT54S



Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	.110	.120	2.80	3.04	
B	.083	.098	2.10	2.64	
C	.047	.055	1.20	1.40	
D	.035	.041	0.89	1.03	
E	.070	.081	1.78	2.05	
F	.018	.024	0.45	0.06	
G	.0005	.0039	0.013	0.100	
H	.035	.044	0.89	1.12	
J	.003	.007	0.085	0.18	
K	.015	.020	0.37	0.51	

SOT-23

Microsemi
Catalog Number

BAT54
BAT54A
BAT54C
BAT54S

Peak Reverse
Voltage

30V
30V
30V
30V

Pin
Configuration

Figure 1
Figure 2
Figure 3
Figure 4

Type

Single
Dual
Dual
Dual

Pin Configuration – Top View

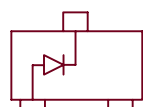


Figure 1 54

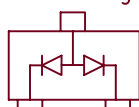


Figure 2 54A

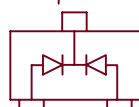


Figure 3 54C

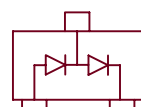


Figure 4 54S

Electrical Characteristics

Total Power Dissipation
Maximum forward voltage drop
Maximum reverse current
Non-repetitive peak forward current
Typical junction capacitance
Reverse recovery time

PD 200 mW
 V_{FM} 0.32 Volts
 V_{FM} 0.50 Volts
 I_R 2.0 μ A
 I_{FSM} 600 mA
CJ 10 pF
 t_{rr} 5 nS

$T_A = 25^\circ\text{C}$
 $I_{FM} = 1\text{mA}$, $T_J = 25^\circ\text{C}^*$
 $I_{FM} = 30\text{mA}$; $T_J = 25^\circ\text{C}^*$
 $V_R = 25\text{V}$, $T_J = 25^\circ\text{C}$
Pulse ≤ 1 second
1.0 MHz, $V_R = 1.0\text{V}$, 25°C
 $I_F = I_R = 10\text{mA}$, $I_{(REC)} = 1\text{mA}$

*Pulse test: Pulse width 300 μ sec, Duty cycle 2%

Thermal and Thermal Characteristics

Storage temperature range
Operating junction temp range
Maximum thermal resistance

T_{STG}
 T_J
 $R_{\theta JA}$

-55°C to 150°C
 -55°C to 125°C
 160°C/W Junction to ambient



SCOTTSDALE

8700 East Thomas Road, P.O. Box 1390
Scottsdale, AZ 85252
PH: (480) 941-6300
FAX: (480) 947-1503
www.microsemi.com

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